AUTOMOTIVE

COMPLIANT HALOGEN

FREE



Vishay Semiconductors

Silicon Phototransistor in 0805 Package



DESCRIPTION

TEMT7000X01 is a high speed silicon NPN epitaxial planar phototransistor in a miniature 0805 package for surface mounting on printed boards. The device is sensitive to visible and near infrared radiation.

FEATURES

• Package type: surface mount

• Package form: 0805

• Dimensions (L x W x H in mm): 2 x 1.25 x 0.85

- AEC-Q101 qualified
- High photo sensitivity
- · High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity: $\varphi = \pm 60^{\circ}$
- Package matched with IR emitter series VSMB1940X01
- Floor life: 168 h, MSL 3, acc. J-STD-020
- · Lead (Pb)-free reflow soldering
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

APPLICATIONS

- Detector in automotive applications
- · Light sensors
- Radiation sensors

PRODUCT SUMMARY			
COMPONENT	I _{caE} (A)	θ (deg)	λ _{0.1} (nm)
TEMT7000X01	225 to 675	± 60	470 to 1090

Note

· Test condition see table "Basic Characteristics"

ORDERING INFORMATION			
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
TEMT7000X01	Tape and reel	MOQ: 3000 pcs, 3000 pcs/reel	0805

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Collector emitter voltage		V _{CEO}	20	V	
Emitter collector voltage		V _{ECO}	7	V	
Collector current		I _C	20	mA	
Power power dissipation	T _{amb} ≤ 55 °C	P _V	100	mW	
Junction temperature		T _j	100	°C	
Operating temperature range		T _{amb}	- 40 to + 100	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	Acc. reflow profile fig. 8	T _{sd}	260	°C	
Thermal resistance junction/ambient	Acc. J-STD-051	R _{thJA}	270	K/W	

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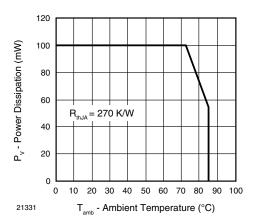


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	$I_{C} = 0.1 \text{ mA}$	V _{CEO}	20			V
Collector dark current	V _{CE} = 5 V, E = 0	I _{CEO}		1	100	nA
Collector emitter capacitance	V _{CE} = 0 V, f = 1 MHz, E = 0	C _{CEO}		25		pF
Collector light current	E_e = 1 mW/cm ² , λ = 950 nm, V_{CE} = 5 V	I _{CA}	225	450	675	μΑ
Angle of half sensitivity		φ		± 60		deg
Wavelength of peak sensitivity		λρ		850		nm
Range of spectral bandwidth		λ _{0.1}		470 to 1090		nm
Collector emitter saturation voltage	$I_{C} = 0.05 \text{ mA}$	V _{CEsat}			0.4	V
Temperature coefficient of Ica	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, \ V_{CE} = 5 \text{ V}$	Tk _{lca}		1.1		%/K

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

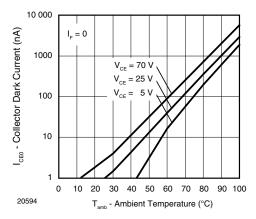


Fig. 2 - Collector Dark Current vs. Ambient Temperature

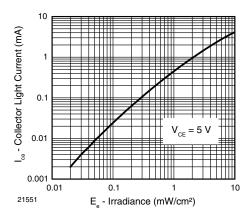


Fig. 3 - Collector Light Current vs. Irradiance



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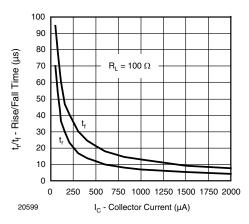


Fig. 4 - Rise/Fall Time vs. Collector Current

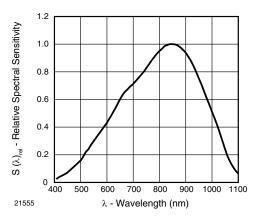


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

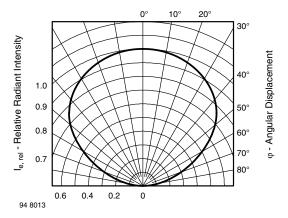


Fig. 6 - Relative Radiant Sensitivity vs. Angular Displacement

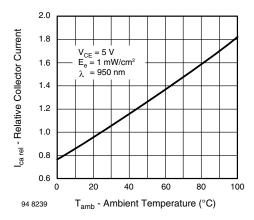


Fig. 7 - Relative Collector Current vs. Ambient Temperature

REFLOW SOLDER PROFILE

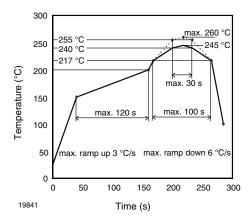


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 168 h

Conditions: T_{amb} < 30 °C, RH < 60 %

Moisture sensitivity level 3, acc. to J-STD-020.

DRYING

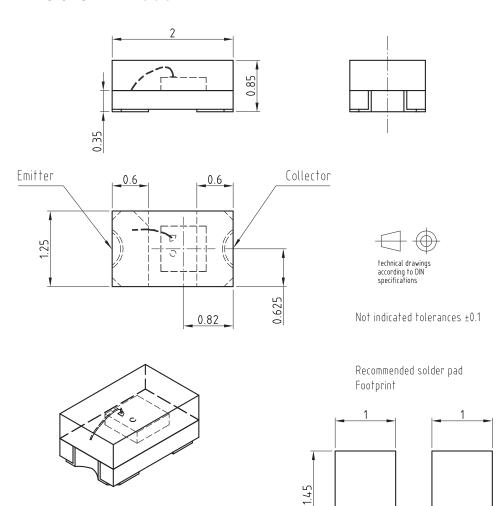
In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

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PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.541-5063.01-4 Issue: 3; 23.02.07

19757

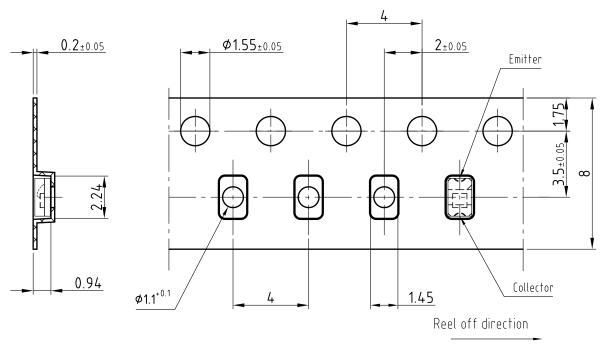
0.6



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BLISTER TAPE DIMENSIONS in millimeters



Drawing-No.: 9.700-5310.01-4

Issue: 2; 14.08.07

20690

Not indicated tolerances ±0.1

Quantity per reel: 3000 pcs



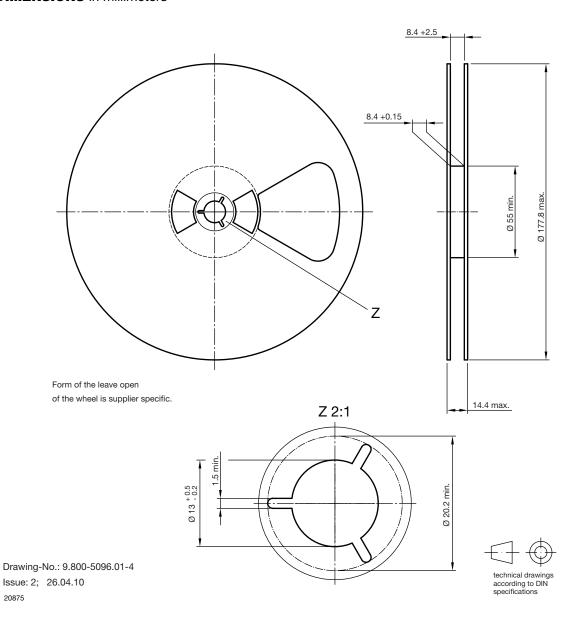
technical drawings according to DIN specifications

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REEL DIMENSIONS in millimeters



20875





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